



# Thyristor Modules MTx600



**$I_{T(AV)}$**  600A  
 **$V_{DRM}/V_{RRM}$**  600~1800V  
 **$I_{TSM}$**   $16A \times 10^3$   
 **$I^2t$**   $1280A^2 S \cdot 10^3$

## Features:

- Isolated mounting base 2500V~
- Pressure contact technology with increased power cycling capability
- Space and weight savings

## Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_f(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=55^{\circ}C$	125			600	A
$I_{T(RMS)}$	RMS on-state current		125			942	A
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage Repetitive peak reverse voltage	$V_{DRM} \& V_{RRM}$ tp=10ms $V_{DSM} \& V_{RSM} = V_{DRM} \& V_{RRM} + 100V$ respectively	125	600		1800	V
$I_{DRM}$ $I_{RRM}$	Repetitive peak current	at $V_{DRM}$ at $V_{RRM}$	125			45	mA
$I_{TSM}$	Surge on-state current	10ms half sine wave	125			16.0	KA
$I^2t$	$I^2T$ for fusing coordination	$V_R=60\%V_{RRM}$				1280	$A^2s \cdot 10^3$
$V_{TO}$	Threshold voltage		125			0.80	V
$r_T$	On-state slop resistance					0.53	$m\Omega$
$V_{TM}$	Peak on-state voltage	$I_{TM}=1800A$	25			1.90	V
$dv/dt$	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			800	$V/\mu s$
$di/dt$	Critical rate of rise of on-state current	Gate source 1.5A $t_r \leq 0.5\mu s$ Repetitive	125			100	$A/\mu s$
$I_{GT}$	Gate trigger current		25	30		200	mA
$V_{GT}$	Gate trigger voltage	$V_A=12V, I_A=1A$		1.0		3.0	V
$I_H$	Holding current			20		200	mA
$V_{GD}$	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.2			V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled				0.073	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case to heat sink	Single side cooled				0.04	$^{\circ}C/W$
$V_{iso}$	Isolation voltage	50Hz,R.M.S, t=1min, $I_{iso}:1mA(MAX)$	2500				V
$F_m$	Thermal connection torque(M10)				12		N·m
	Mounting torque(M6)				6		N·m
$T_{stg}$	Stored temperature		-40			125	$^{\circ}C$
$W_t$	Weight				1820		g
Outline							

Peak On-state Voltage Vs. Peak On-state Current

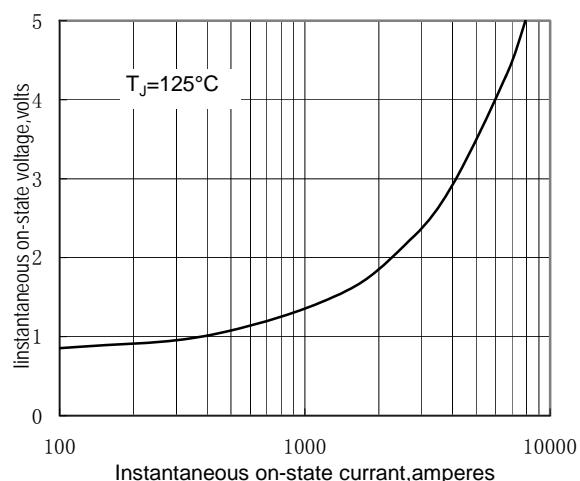


Fig.1

Max. junction To case Thermal Impedance Vs. Time

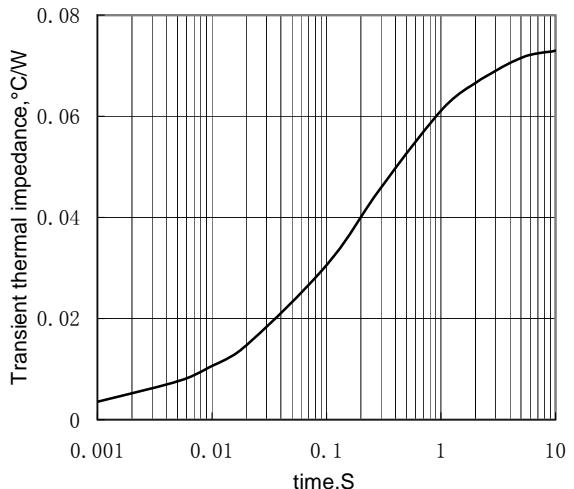


Fig.2

Max. Power Dissipation Vs. Mean On-state Current

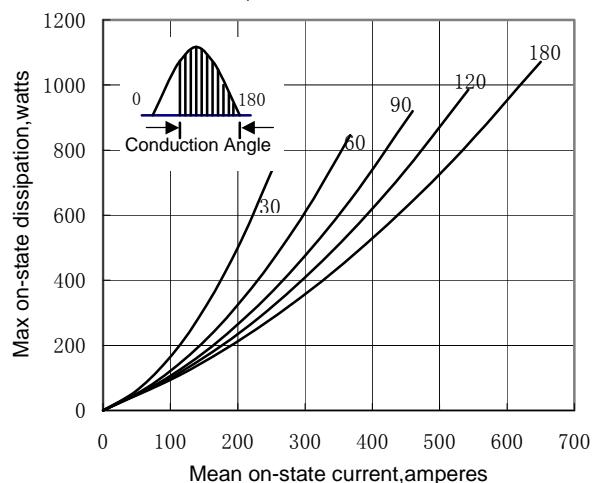


Fig.3

Max. case Temperature Vs. Mean On-state Current

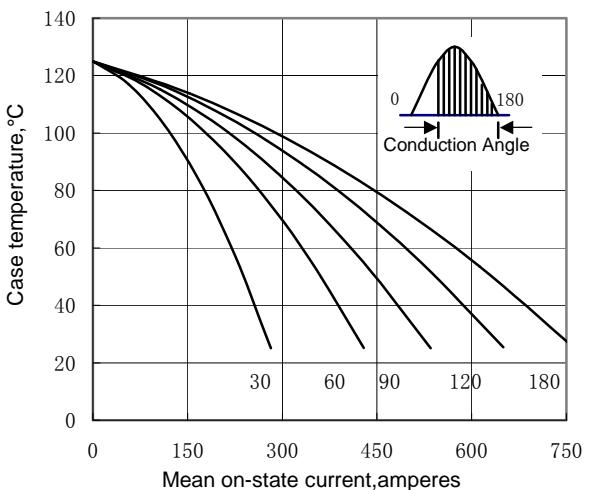


Fig.4

Max. Power Dissipation Vs. Mean On-state Current

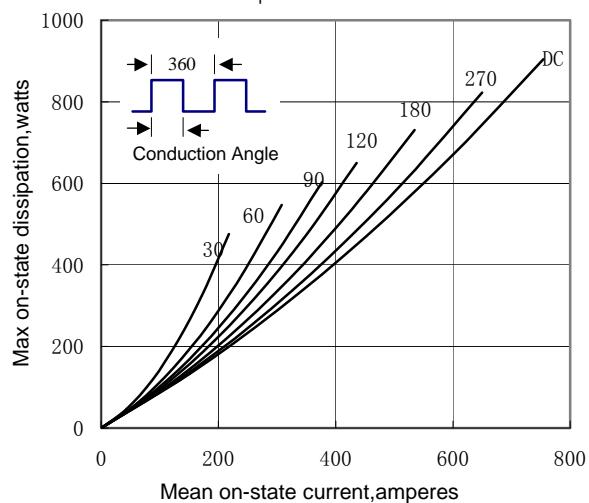


Fig.5

Max. case Temperature Vs. Mean On-state Current

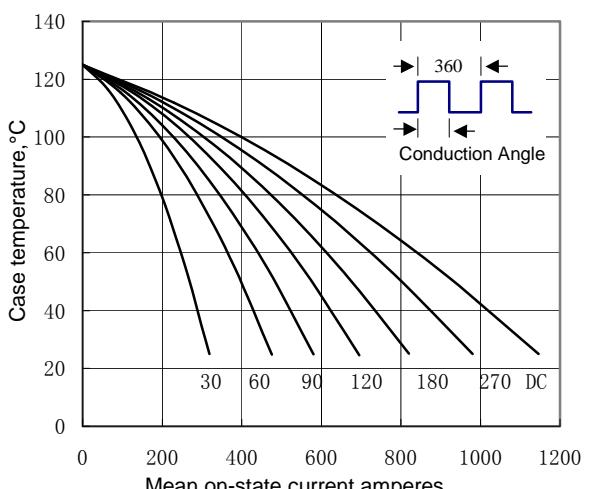


Fig.6

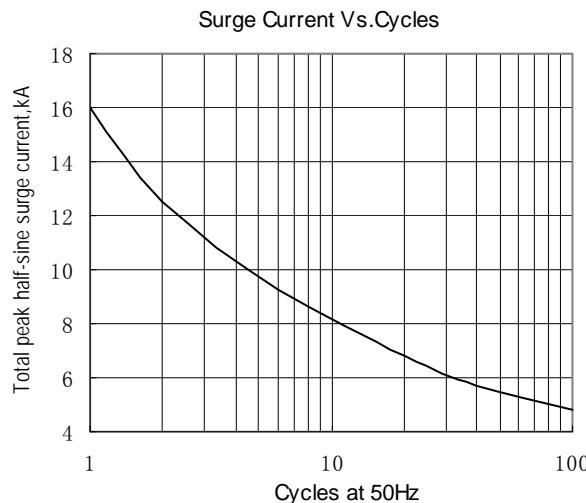


Fig.7

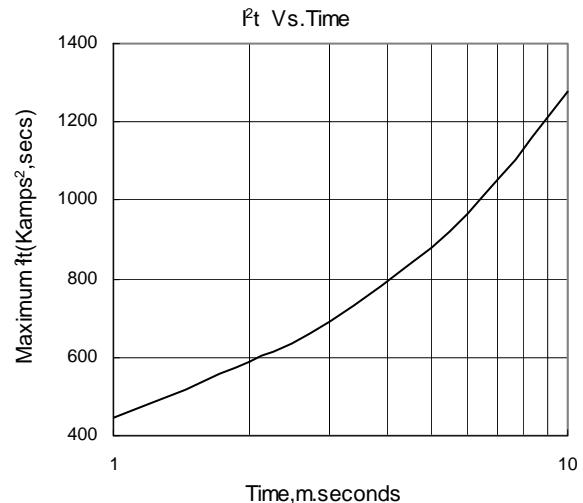


Fig.8

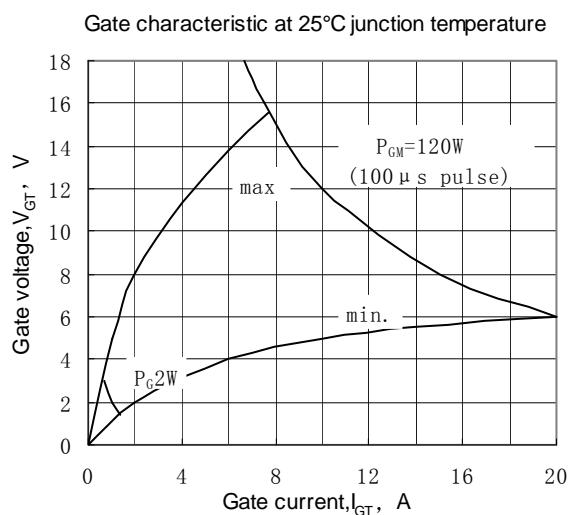


Fig.9

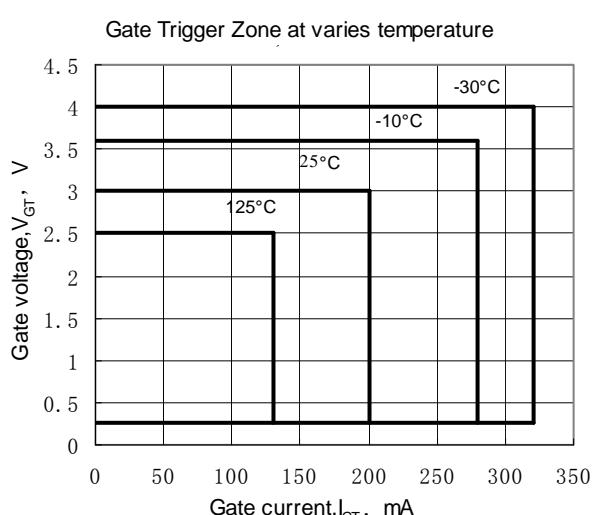


Fig.10

### Outline:

